

AH201 HALL-EFFECT SWITCH INTEGRATED CIRCUITS

These Hall-effect switch integrated circuits are monolithic integrated circuit consisting of a voltage regulator, Hall-voltage generator, differential amplifier, schmitt trigger, temperature compensation circuit and open-collector output stage. Its input is a magnetic flux density signal and output is a digital voltage signal.

FEATURES

- . Wide supply voltage range
- . Fast response time
- . Wide frequency and temperature range
- . Long operating life
- . Small size, convenient installing
- . Output compatible with all digital logic families

TYPICAL APPLICATIONS

- . Contactless switch
- . Speed measurement
- . Isolation measurement
- . Automotive ignitor
- . Position control
- . Revolution detection
- . Brushless d.c motor

ABSOLUTE MAXIMUM RATING

Parameter	Symbol	Value	Unit
Supply voltage	V _{CC}	24	V
Magnetic flux density	B	Unlimited	mT
Output OFF voltage	V _{ce}	50	V
Continuous output current	I _{OL}	50	mA
Operating temperature range	T _A	-25~85	°C
Storage temperature range	T _S	-55~150	°C

ELECTRICAL CHARACTERISTICS

T_A=25°C

Parameter	Symbol	Test condition	Type and Value			Unit
			min	typ	max	
Supply voltage	V _{CC}		4.5	-	24	V
Output saturation voltage	V _{OL}	I _{out} =20mA B>B _{OP}	-	200	400	mV
Output leakage current	I _{OH}	V _{out} =24V B<B _{RP}	-	0.1	10	μA
Supply current	I _{CC}	V _{CC} =Output open	-	-	10	mA
Output rise time	t _r	R _L =820 Ω C _L =20PF	-	0.12	-	μS
Output fall time	t _f	R _L =820 Ω C _L =20PF	-	0.18	-	μS

MAGNET CHARACTERISTICS

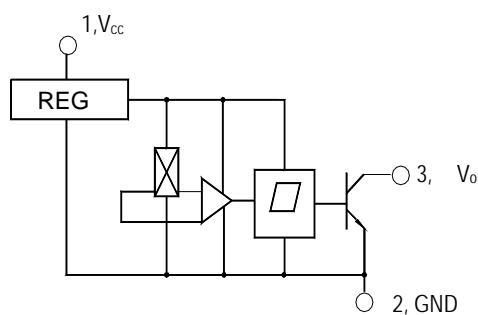
V_{CC}=4.5~24V

Parameter	Symbol	Type and Value			Unit
		min	typ	max	
Operate point	B _{OP}			11	mT
Release point	B _{RP}	2			mT
Hysteresis	B _H		5	-	mT

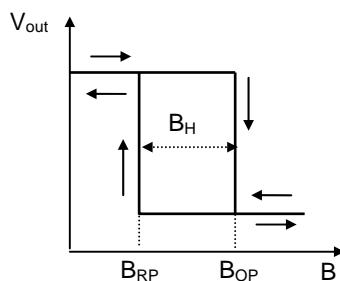
NOTE: 1mT=10GS

HALL SENSORS

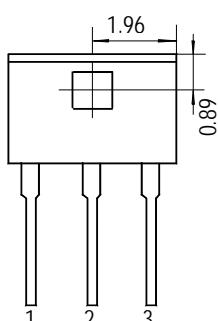
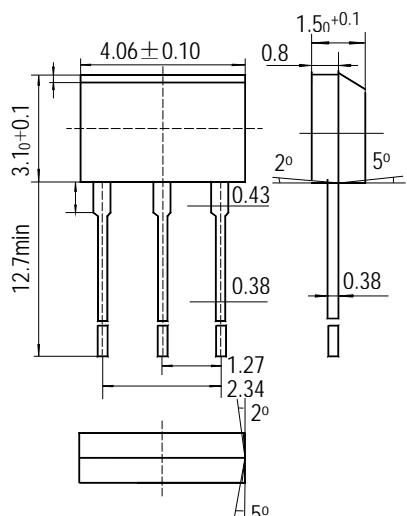
BLOCK DIAGRAM



MAGNETIC-ELECTRICAL TRANSFER CHARACTERISTICS

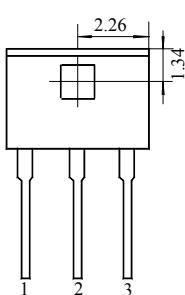
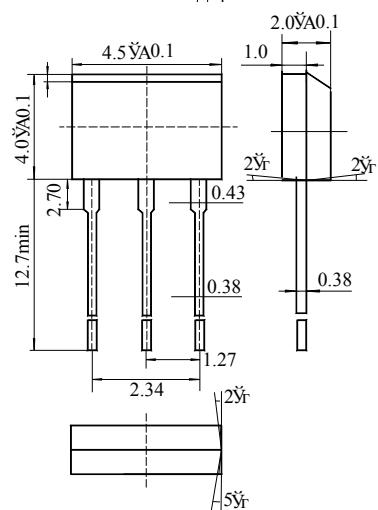


DIMENSIONS (in: mm)



1. V_{cc} 2. GND 3. OUTPUT

TO -92UA Package and Active Area



V_{cc} 2. GND 3. OUTPUT

TO -92T Package and Active Area

Cautions

- When install, should as full as possible decrease the mechanical stress acting on the Hall IC, to avoid the influence of the operate point and release point.
- On the premise of ensuring welding quality, use as possible as low welding temperature as short time.

